Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.656 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do5

Mounting Method:

Threaded stud

Features Provided:

Electrostatic sensitive and hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

35.0 working peak reverse voltage and 35.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

75.00 amperes forward current, average

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 1 uninsulated wire lead w/terminal lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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